NSN 5961-01-333-1456

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-333-1456 **Inclosure Material:** Metal **Overall Length:** Between 0.250 inches and 0.450 inches **Overall Height:** Between 1.177 inches and 1.197 inches Overall Width: 1.050 inches **Function For Which Designed:** Rectifier **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Component Name And Quantity:** 4 semiconductor device diode **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 400.0 reverse voltage, peak all semiconductor device diode **Current Rating Per Characteristic:** 30.00 amperes forward current, average absolute all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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